

Analog Devices Welcomes Hittite Microwave Corporation

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HMC175* Product Page Quick Links

Last Content Update: 11/01/2016

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Data Sheet

- HMC175 Data Sheet

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[Reference Materials](#)

Quality Documentation

- HMC Legacy PCN: MS##, MS##E and MS##G,MS##GE packages - Relocation of pre-existing production equipment to new building
- Package/Assembly Qualification Test Report: Plastic Encapsulated MSOP (QTR: 02016 REV: 01)
- PCN: MS, QS, SOT, SOIC packages - Sn/Pb plating vendor change
- Semiconductor Qualification Test Report: MESFET-B (QTR: 2013-00245)

[Design Resources](#)

- HMC175 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

[Discussions](#)

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Submit a technical question or find your regional support number

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Typical Applications

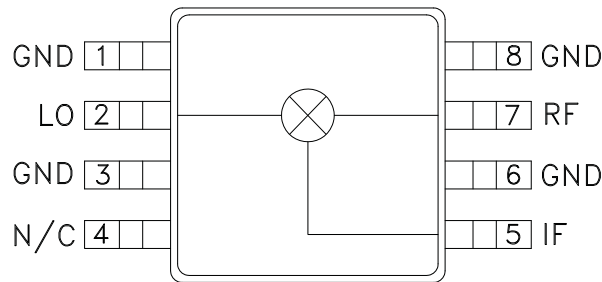
The HMC175MS8 / HMC175MS8E is ideal for:

- Mini-Base Stations
- Portable Wireless
- PCMCIA

Features

- Ultra Small Package: MSOP8
- Conversion Loss: 8 dB
- LO / IF Isolation: 32 dB
- LO / RF Isolation: 30 dB
- Input IP3: +18 dBm

Functional Diagram



General Description

The HMC175MS8 & HMC175MS8E are miniature double-balanced mixers in 8-lead plastic surface mount Mini Small Outline Packages (MSOP). The device can be used as an upconverter or downconverter. The mixer provides exceptional isolation and Intermodulation performance for applications in high signal density environments. This device can also be used as a biphase modulator or demodulator. The MSOP8 is the smallest footprint available for a complete double-balanced mixer (0.118" x 0.190" x 0.040").

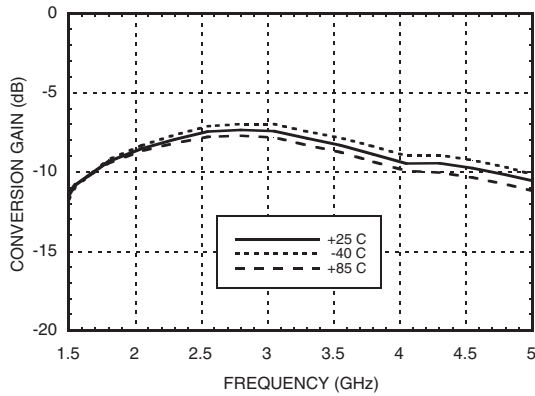
Electrical Specifications, $T_A = +25^\circ \text{C}$, LO Drive = +13 dBm

Parameter	Broadband			PCS Band			ISM Band			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range, RF & LO	1.7 - 4.5			1.7 - 2.0			2.2 - 2.6			GHz
Frequency Range, IF	DC - 1.0			DC - 1.0			DC - 1.0			GHz
Conversion Loss		8	11		9	11		8	10	dB
Noise Figure (SSB)		8	11		9	11		8	10	dB
LO to RF Isolation	25	30		35	40		30	35		dB
LO to IF Isolation	27	32		28	32		28	32		dB
IP3 (Input)	15	20		15	18		15	18		dBm
1 dB Gain Compression (Input)	9	12		9	11		9	11		dBm

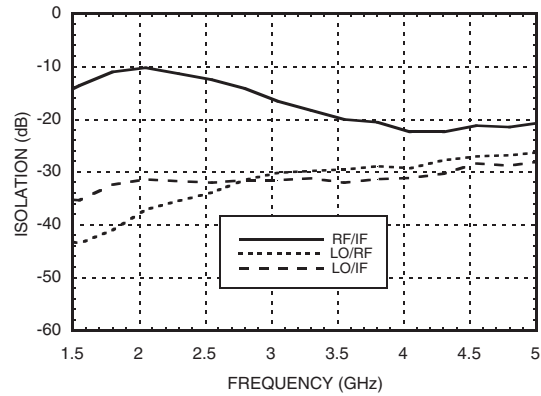


GaAs MMIC SMT DOUBLE-BALANCED MIXER, 1.7 - 4.5 GHz

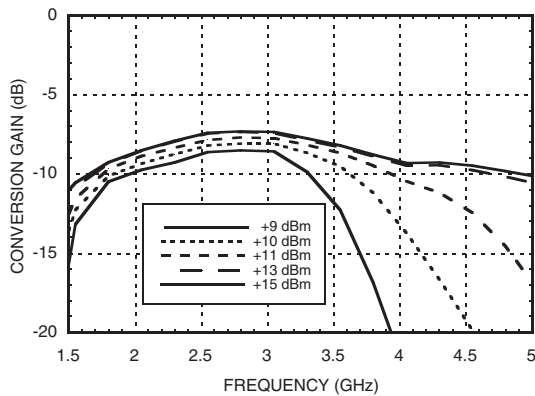
Conversion Gain vs Temperature @ LO = +13 dBm



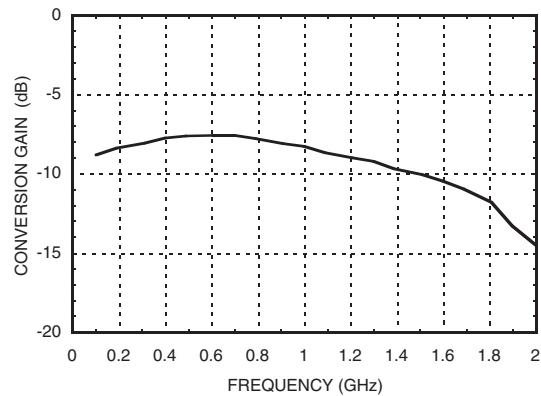
Isolation @ LO = +13 dBm



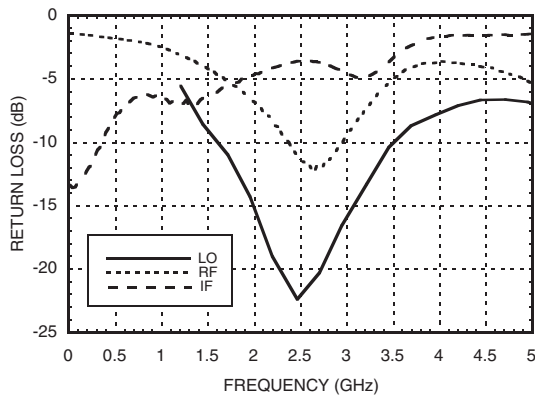
Conversion Gain vs LO Power



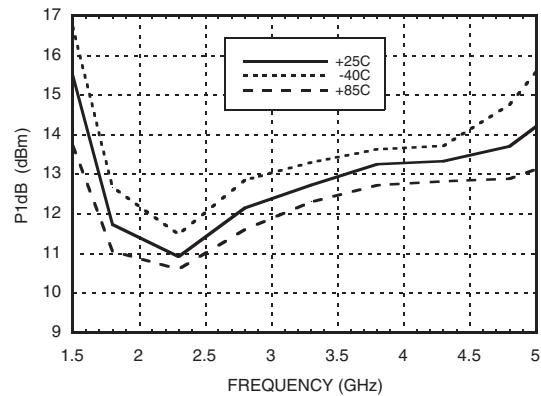
IF Bandwidth @ LO = +13 dBm



Return Loss @ LO = +13 dBm



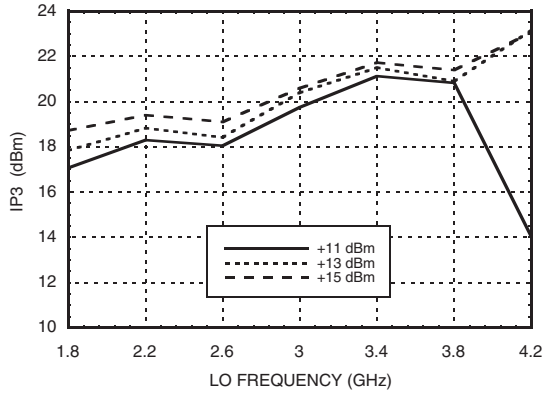
P1dB vs Temperature @ LO = +13 dBm



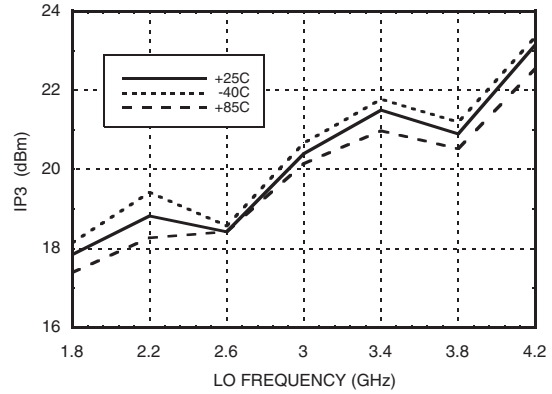


GaAs MMIC SMT DOUBLE-BALANCED MIXER, 1.7 - 4.5 GHz

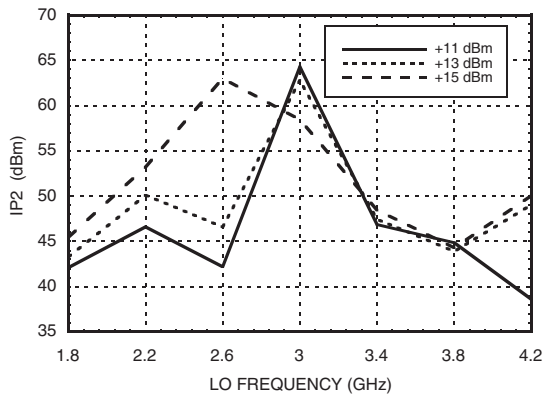
Input IP3 vs. LO Drive



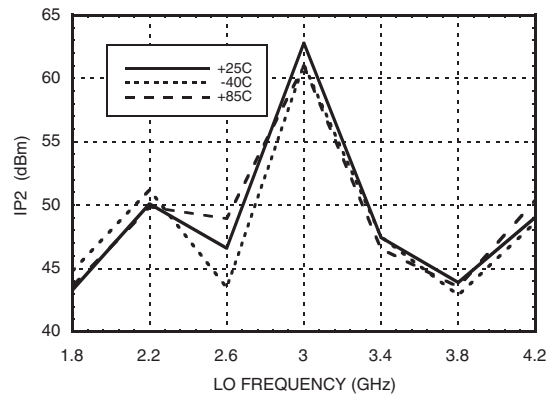
Input IP3 vs. Temperature @ LO = +13 dBm



Input IP2 vs. LO Drive



Input IP2 vs. Temperature @ LO = +13 dBm



MxN Spurious Outputs

RF Frequency = 2.3 GHz @ -10 dBm					
LO Frequency = 2.4 GHz @ 13 dBm					
		nLO			
mRF	0	1	2	3	4
0	xx	1	12	12	37
1	4	0	27	39	38
2	74	53	56	60	67
3	78	>105	73	72	79
4	>105	>105	>105	>105	>105

All values in dBc below IF power level.

Harmonics of LO

LO Freq. (GHz)	nLO Spur at RF Port			
	1	2	3	4
1.8	37	32	63	53
2.2	35	30	37	63
2.6	32	28	33	55
3	30	29	53	52
3.1	29	30	56	51
3.6	29	39	52	53
4.2	27	46	48	61

LO = +13 dBm
Values in dBc below input LO level measured at RF Port.

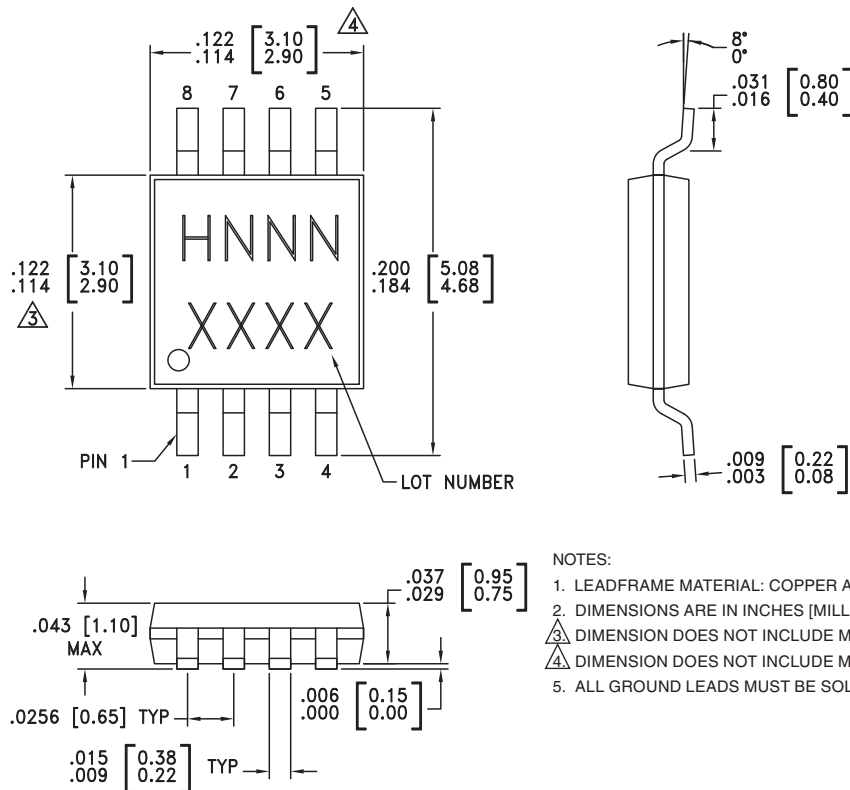
Absolute Maximum Ratings

RF / IF Input	+13 dBm
LO Drive	+27 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC175MS8	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H175 XXXX
HMC175MS8E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H175 XXXX

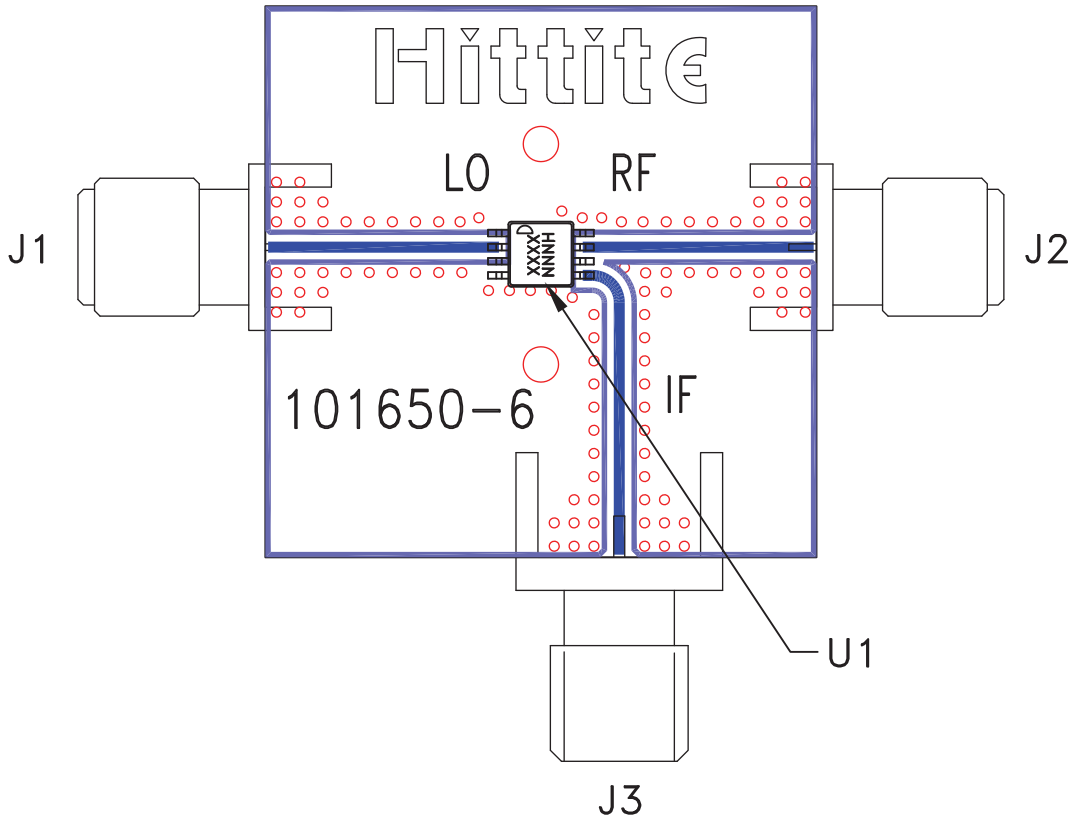
[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
 Order On-line at www.hittite.com

Evaluation Circuit Board



List of Materials for Evaluation PCB 103350 [1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
U1	HMC175MS8 / HMC175MS8E Mixer
PCB [2]	101650 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



HMC175MS8 / 175MS8E

**GaAs MMIC SMT DOUBLE-
BALANCED MIXER, 1.7 - 4.5 GHz**

Notes: